

S30SC4M

40V 30A

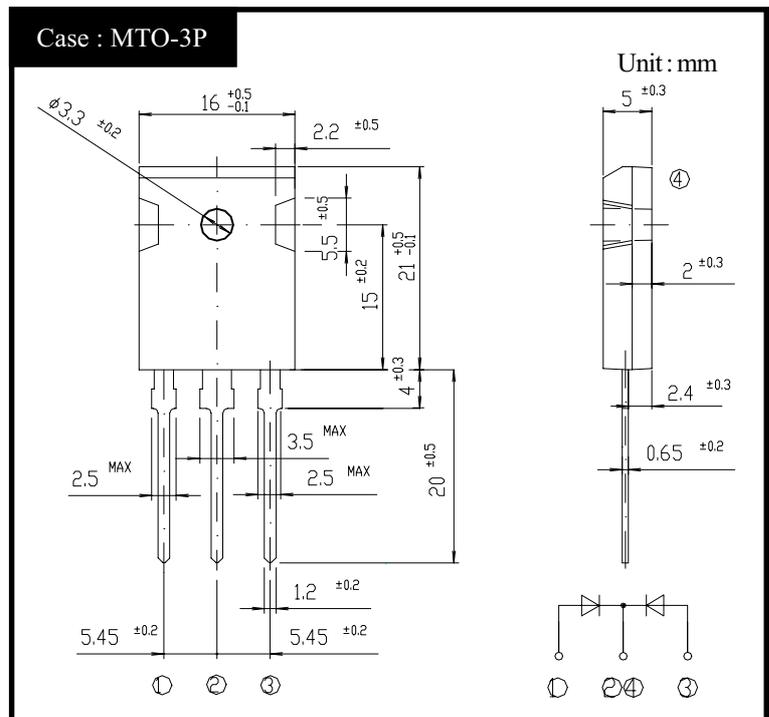
FEATURES

- $T_j 150^{\circ}\text{C}$
- P_{RRSM} avalanche guaranteed
- Small θ_{jc}
- High current capacity

APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings (If not specified $T_c=25^{\circ}\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40~150	$^{\circ}\text{C}$
Operating Junction Temperature	T_j		150	$^{\circ}\text{C}$
Maximum Reverse Voltage	V_{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load, Rating for each diode $I_o/2$, $T_c=126^{\circ}\text{C}$	30	A
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j=125^{\circ}\text{C}$	300	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10 μ s, Rating of per diode, $T_j=25^{\circ}\text{C}$	1000	W
Mounting Torque	TOR	(Recommended torque: 0.5N·m)	0.8	N·m

● Electrical Characteristics (If not specified $T_c=25^{\circ}\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=15\text{A}$, Pulse measurement, Rating of per diode	Max.0.55	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.10	mA
Junction Capacitance	C_j	$f=1\text{MHz}$, $V_R=10\text{V}$, Rating of per diode	Typ.590	pF
Thermal Resistance	θ_{jc}	junction to case	Max.1.0	$^{\circ}\text{C}/\text{W}$

S30SC4M Junction Capacitance



Reverse Voltage V_R [V]

0.05 0.2 0.5 2 5 20 50 200 500 2000 5000

0.002 0.005 0.02 0.05 0.2 0.5 2 5 20

Made in China